# 2SC4111

## Silicon NPN triple diffusion planar type

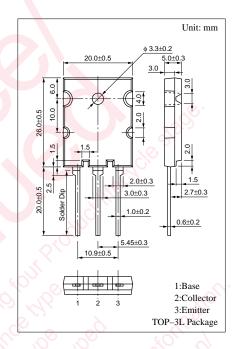
#### For horizontal deflection output

#### Features

- High-speed switching
- High collector to base voltage V<sub>CBO</sub>
- Wide area of safe operation (ASO)
- Satisfactory linearity of foward current transfer ratio h<sub>FE</sub>

### Absolute Maximum Ratings (T<sub>C</sub>=25°C)

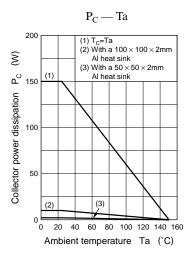
Parameter	Symbol	Ratings	Unit	
Collector to base voltage	$V_{CBO}$	1500	V	
C-11	V <sub>CES</sub>	1500	V	
Collector to emitter voltage	V <sub>CEO</sub>	700	V	
Emitter to base voltage	V <sub>EBO</sub> 7		V	
Peak collector current	$I_{CP}$	22	A	
Collector current	$I_{\rm C}$	10	A	
Base current	$I_{\mathrm{B}}$	3.5	A	
Collector power T <sub>C</sub> =25°C	D	150	GW G	
dissipation Ta=25°C	$P_{C}$	3.5	w.X	
Junction temperature	$T_{\rm j}$	150	°C	
Storage temperature	$T_{ m stg}$	-55 to +150	°C (0	

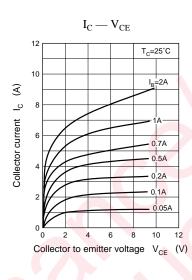


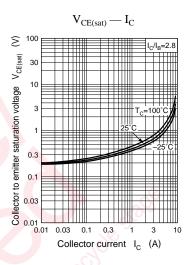
### Electrical Characteristics (T<sub>C</sub>=25°C)

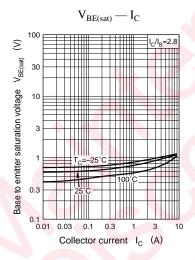
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = 750V, I_E = 0$	O		10	μΑ
		$V_{CB} = 1500V, I_E = 0$			1	mA
Emitter to base voltage	V <sub>EBO</sub>	$I_C = 1 \text{mA}, I_B = 0$	7			V
Forward current transfer ratio	h <sub>FE1</sub>	$V_{CE} = 5V, I_C = 1A$	5			
	h <sub>FE2</sub>	$V_{CE} = 5V, I_C = 7A$	3		8	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 7A, I_B = 2.5A$			5	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_C = 7A, I_B = 2.5A$			1.5	V
Transition frequency	$f_T$	$V_{CE} = 10V, I_{C} = 1A, f = 0.5MHz$		2		MHz
Storage time	t <sub>stg</sub>	$I_{C} = 6A, L_{leak} = 5\mu H,$			12	μs
Fall time	$t_{\rm f}$	$I_{B1} = 1.7A, I_{B2} = -1.7A$			0.6	μs

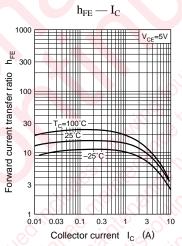
Power Transistors 2SC4111

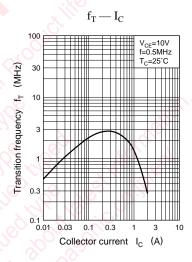


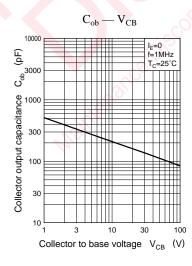


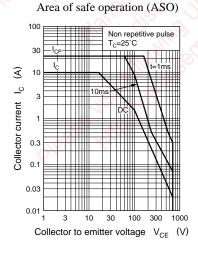


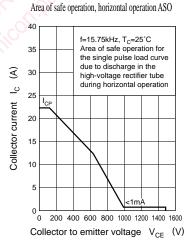






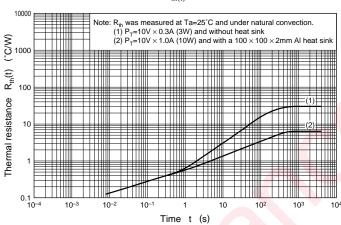






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